NSN 5962-01-286-2245

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View Online at https://aerobasegroup.com/nsn/5962-01-286-2245

Body Length: 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 880.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and bipolar and programmable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** -30.00 milliamperes input and 5.00 milliamperes input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts applied **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Prom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 printed circuit Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A458a0

